# Silicon Carbide Schottky Diode

1200 V, 30 A

# **FFSH30120A**

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### **Features**

- Max Junction Temperature 175°C
- Avalanche Rated 361 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

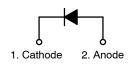
#### **Applications**

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

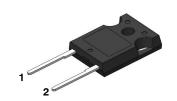


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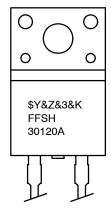


**Schottky Diode** 



TO-247-2LD CASE 340CL

#### **MARKING DIAGRAM**



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code &K = Lot Code

FFSH30120A = Specific Device Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# **ABSOLUTE MAXIMUM RATINGS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage	1200	V	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	Single Pulse Avalanche Energy (Note 1)		
I <sub>F</sub>	Continuous Rectified Forward Current @ T <sub>C</sub> <	30	Α	
	Continuous Rectified Forward Current @ T <sub>C</sub> < 135°C			
I <sub>F, Max</sub>	Non-Repetitive Peak Forward Surge Current	T <sub>C</sub> = 25°C, 10 μs	1500	Α
		T <sub>C</sub> = 150°C, 10 μs	1400	Α
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	230	Α
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Repetitive Forward Surge Current Half-Sine Pulse, t <sub>p</sub> = 8.3 ms		Α
Ptot	Power Dissipation	T <sub>C</sub> = 25°C	500	W
		T <sub>C</sub> = 150°C	83	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range TO247 Mounting Torque, M3 Screw		-55 to +175	°C
			60	Ncm

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E<sub>AS</sub> of 361 mJ is based on starting T<sub>J</sub> = 25°C, L = 0.5 mH, I<sub>AS</sub> = 38 A, V = 50 V.

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{ heta JC}$	Thermal Resistance, Junction to Case, Max	0.3	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
$V_{F}$	Forward Voltage	I <sub>F</sub> = 30 A, T <sub>C</sub> = 25°C	-	1.45	1.75	V
		I <sub>F</sub> = 30 A, T <sub>C</sub> = 125°C	-	1.7	2.0	
		I <sub>F</sub> = 30 A, T <sub>C</sub> = 175°C	-	2.0	2.4	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 1200 V, T <sub>C</sub> = 25°C	-	=	200	μΑ
		V <sub>R</sub> = 1200 V, T <sub>C</sub> = 125°C	-	=	300	
		V <sub>R</sub> = 1200 V, T <sub>C</sub> = 175°C	-	=	400	
$Q_{\mathbb{C}}$	Total Capacitive Charge	V = 800 V	-	175	=	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	1740	=	pF
		V <sub>R</sub> = 400 V, f = 100 kHz	-	159	-	
		V <sub>R</sub> = 800 V, f = 100 kHz	-	130	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Part Number	Top Marking	Package	Shipping
FFSH30120A	FFSH30120A	TO-247-2LD (Pb-Free)	30 Units / Tube

### **TYPICAL CHARACTERISTICS**

(T<sub>J</sub> = 25°C unless otherwise noted)

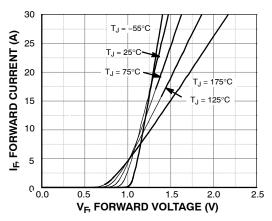


Figure 1. Forward Characteristics

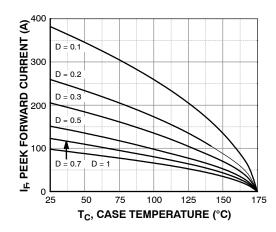


Figure 3. Current Derating

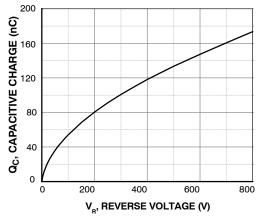


Figure 5. Capacitive Charge vs. Reverse Voltage

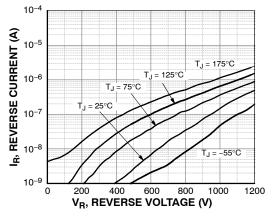


Figure 2. Reverse Characteristics

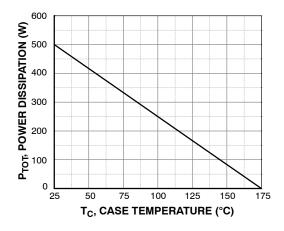


Figure 4. Power Derating

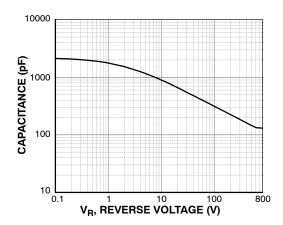


Figure 6. Capacitance vs. Reverse Voltage

# **TYPICAL CHARACTERISTICS**

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ 

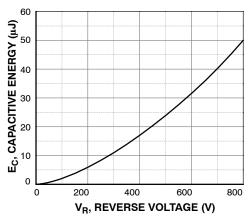


Figure 7. Capacitance Stored Energy

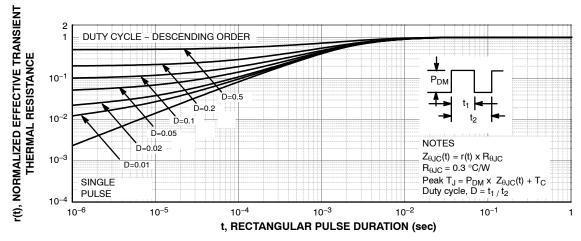


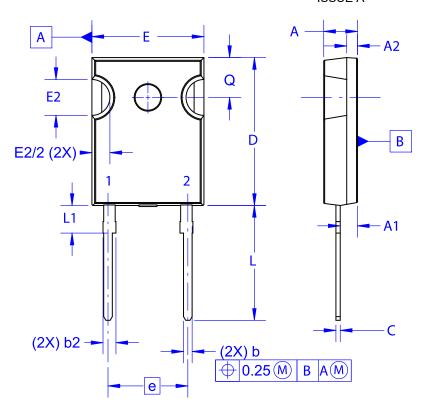
Figure 8. Junction-to-Case Transient Thermal Response Curve

# **TEST CIRCUIT AND WAVEFORMS**

L = 0.5 mH  $R < 0.1 \Omega$   $V_{DD} = 50 \text{ V}$   $EAVL = 1/2LI2 \left[ V_{R(AVL)} / \left( V_{R(AVL)} - V_{DD} \right) \right]$   $Q1 = IGBT \left( BV_{CES} > DUT V_{R(AVL)} \right)$   $V_{AVL}$  CURRENT SENSE  $V_{DD}$  DUT  $V_{DD}$   $V_{DD}$   $V_{DD}$   $V_{DD}$   $V_{DD}$   $V_{DD}$ 

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

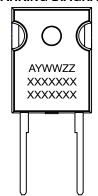
#### TO-247-2LD CASE 340CL **ISSUE A**





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
  D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

#### **GENERIC MARKING DIAGRAM\***



XXXX = Specific Device Code

= Assembly Location

= Year

WW = Work Week

= Assembly Lot Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

	DATE 03 E	
Ø P —		Ø P1 D2
E1 —	1	D1
,		9

DIM	MILLIMETERS			
	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
A1	2.29	2.40	2.66	
A2	1.30	1.50	1.70	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
С	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	16.37	16.57	16.77	
D2	0.51	0.93	1.35	
Е	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	~	11.12	~	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØΡ	3.51	3.58	3.65	
ØP1	6.61	6.73	6.85	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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DESCRIPTION:	TO-247-2LD		PAGE 1 OF 1	

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